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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	86184
Total RAM Bits	2648064
Number of I/O	267
Number of Gates	-
Voltage - Supply	1.14V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2gl090ts-1fg484

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1 Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

1.1 Revision 11.0

The following is a summary of the changes in revision 11.0 of this document.

- Updated [Table 24](#), page 22 with minimum and maximum values for input current low and high (SAR 73114 and 80314).
- Added [Non-Deterministic Random Bit Generator \(NRBG\) Characteristics](#), page 106 (SAR 73114 and 79517).
- Added 060 device in [Table 282](#), page 110 (SAR 79860).
- Added [DEVRST_N to Functional Times](#), page 116 (SAR 73114).
- Added [Cryptographic Block Characteristics](#), page 106 (SAR 73114 and 79516).
- Update [Table 296](#), page 121 with VTX-AMP details (SAR 81756).
- Update note in [Table 297](#), page 122 (SAR 74570 and 80677).
- Update [Table 298](#), page 122 with generic EPICS details (SAR 75307).
- Added [Table 308](#), page 129 (SAR 50424).

1.2 Revision 10.0

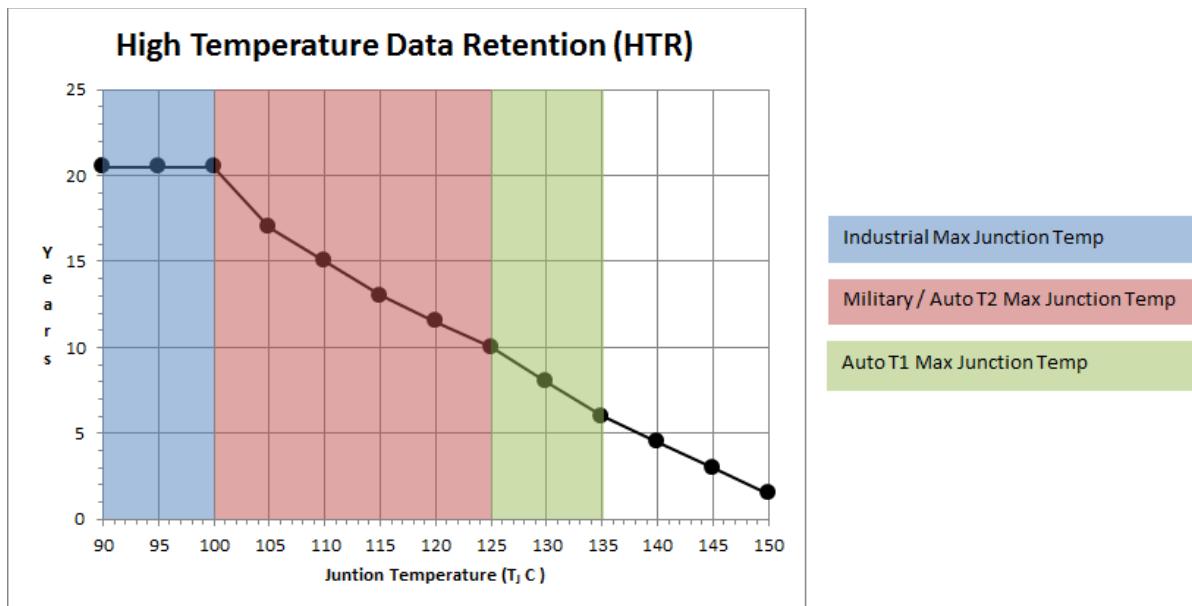
The following is a summary of the changes in revision 10.0 of this document.

- The Surge Current on VDD during DEVRST_B Assertion and Surge Current on VDD during Digest Check using System Services tables were deleted and added reference to [AC393: Board Design Guidelines for SmartFusion2 SoC and IGLOO2 FPGAs Application Note](#). (SAR 76865 and 76623).
- Added 060 device in [Table 4](#), page 6 (SAR 76383).
- Updated [Table 24](#), page 22 for ramp time input (SAR 72103).
- Added 060 device details in [Table 284](#), page 112 (SAR 74927).
- Updated [Table 290](#), page 116 for name change (SAR 74925).
- Updated [Table 283](#), page 111 for 060 FG676 Package details (SAR 78849).
- Updated [Table 305](#), page 126 for SmartFusion2 and [Table 310](#), page 129 for IGLOO2 for SPI timing and Fmax (SAR 56645, 75331).
- Updated [Table 293](#), page 119 for Flash*Freeze entry and exit times (SAR 75329, 75330).
- Updated [Table 297](#), page 122 for RX-CID information (SAR 78271).
- Added [Table 8](#), page 8 and [Figure 1](#), page 9 (SAR 78932).
- Updated [Table 223](#), page 76 for timing characteristics and [Table 224](#), page 77(SAR 75998).
- Added [SRAM PUF](#), page 105 (SAR 64406).
- Added a footnote on digest cycle in [Table 5](#), page 7 (SAR 79812).

1.3 Revision 9.0

The following is a summary of the changes in revision 9.0 of this document.

- Added a note in [Table 5](#), page 7 (SAR 71506).
- Added a note in [Table 6](#), page 8 (SAR 74616).
- Added a note in [Figure 3](#), page 17 (SAR 71506).
- Updated Quiescent Supply Current for 060 in [Table 11](#), page 12 and [Table 12](#), page 13 (SAR 74483).
- Updated programming currents for 060 in [Table 13](#), page 13, [Table 14](#), page 13, and [Table 15](#), page 14.
- Added DEVRST_B assertion tables (SAR 74708).
- Updated I/O speeds for LVDS 3.3 V in [Table 18](#), page 19 and [Table 21](#), page 20 (SAR 69829).
- Updated [Table 24](#), page 22 (SAR 69418).
- Updated [Table 25](#), page 22, [Table 26](#), page 23, [Table 27](#), page 23 (SAR 74570).
- Updated all AC/DC table to link to the [Input Capacitance, Leakage Current, and Ramp Time](#), page 22 for reference (SAR 69418).

Figure 1 • High Temperature Data Retention (HTR)

2.3.1.1 Overshoot/Undershoot Limits

For AC signals, the input signal may undershoot during transitions to -1.0 V for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

For AC signals, the input signal may overshoot during transitions to $V_{CC1} + 1.0\text{ V}$ for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

Note: The above specifications do not apply to the PCI standard. The IGLOO2 and SmartFusion2 PCI I/Os are compliant with the PCI standard including the PCI overshoot/undershoot specifications.

2.3.1.2 Thermal Characteristics

The temperature variable in the Microsemi SoC Products Group Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption causes the chip's junction temperature to be higher than the ambient, case, or board temperatures.

EQ1 through EQ3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - T_A}{P} \quad EQ\ 1$$

$$\theta_{JB} = \frac{T_J - T_B}{P} \quad EQ\ 2$$

$$\theta_{JC} = \frac{T_J - T_C}{P} \quad EQ\ 3$$

Table 17 • Timing Model Parameters (continued)

Index	Symbol	Description	-1	Unit	For More Information
F	T _{DP}	Propagation delay of an OR gate	0.179	ns	See Table 223, page 76
G	T _{DP}	Propagation delay of an LVDS transmitter	2.136	ns	See Table 169, page 57
H	T _{DP}	Propagation delay of a three-input XOR Gate	0.241	ns	See Table 223, page 76
I	T _{DP}	Propagation delay of LVCMOS 2.5 V transmitter, drive strength of 16 mA on the MSIO bank	2.412	ns	See Table 46, page 27
J	T _{DP}	Propagation delay of a two-input NAND gate	0.179	ns	See Table 223, page 76
K	T _{DP}	Propagation delay of LVCMOS 2.5 V transmitter, drive strength of 8 mA on the MSIO bank	2.309	ns	See Table 46, page 27
L	T _{CLKQ}	Clock-to-Q of the data register	0.108	ns	See Table 224, page 77
	T _{SUD}	Setup time of the data register	0.254	ns	See Table 224, page 77
M	T _{DP}	Propagation delay of a two-input AND gate	0.179	ns	See Table 223, page 76
N	T _{OCLKQ}	Clock-to-Q of the output data register	0.263	ns	See Table 220, page 69
	T _{OSUD}	Setup time of the output data register	0.19	ns	See Table 220, page 69
O	T _{DP}	Propagation delay of SSTL2, Class I transmitter on the MSIO bank	2.055	ns	See Table 114, page 45
P	T _{DP}	Propagation delay of LVCMOS 1.5 V transmitter, drive strength of 12 mA, fast slew on the DDRIO bank	3.316	ns	See Table 70, page 34

2.3.5.6 Single-Ended I/O Standards

2.3.5.6.1 Low Voltage Complementary Metal Oxide Semiconductor (LVCMOS)

LVCMOS is a widely used switching standard implemented in CMOS transistors. This standard is defined by JEDEC (JESD 8-5). The LVCMOS standards supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs are: LVCMOS12, LVCMOS15, LVCMOS18, LVCMOS25, and LVCMOS33.

2.3.5.6.2 3.3 V LVCMOS/LVTTL

LVCMOS 3.3 V or Low-Voltage Transistor-Transistor Logic (LVTTL) is a general standard for 3.3 V applications.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 29 • LVTTL/LVCMOS 3.3 V DC Recommended DC Operating Conditions (Applicable to MSIO I/O Bank Only)

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{DDI}	3.15	3.3	3.45	V

Table 30 • LVTTL/LVCMOS 3.3 V Input Voltage Specification (Applicable to MSIO I/O Bank Only)

Parameter	Symbol	Min	Max	Unit
DC input logic high	V_{IH} (DC)	2.0	3.45	V
DC input logic low	V_{IL} (DC)	-0.3	0.8	V
Input current high ¹	I_{IH} (DC)			
Input current low ¹	I_{IL} (DC)			

1. See Table 24, page 22.

Table 31 • LVCMOS 3.3 V DC Output Voltage Specification (Applicable to MSIO I/O Bank Only)

Parameter	Symbol	Min	Max	Unit
DC output logic high ¹	V_{OH}	$V_{DDI} - 0.4$		V
DC output logic low ¹	V_{OL}		0.4	V

1. The V_{OH}/V_{OL} test points selected ensure compliance with LVCMOS 3.3 V JESD8-B requirements.

Table 32 • LVTTL 3.3 V DC Output Voltage Specification (Applicable to MSIO I/O Bank Only)

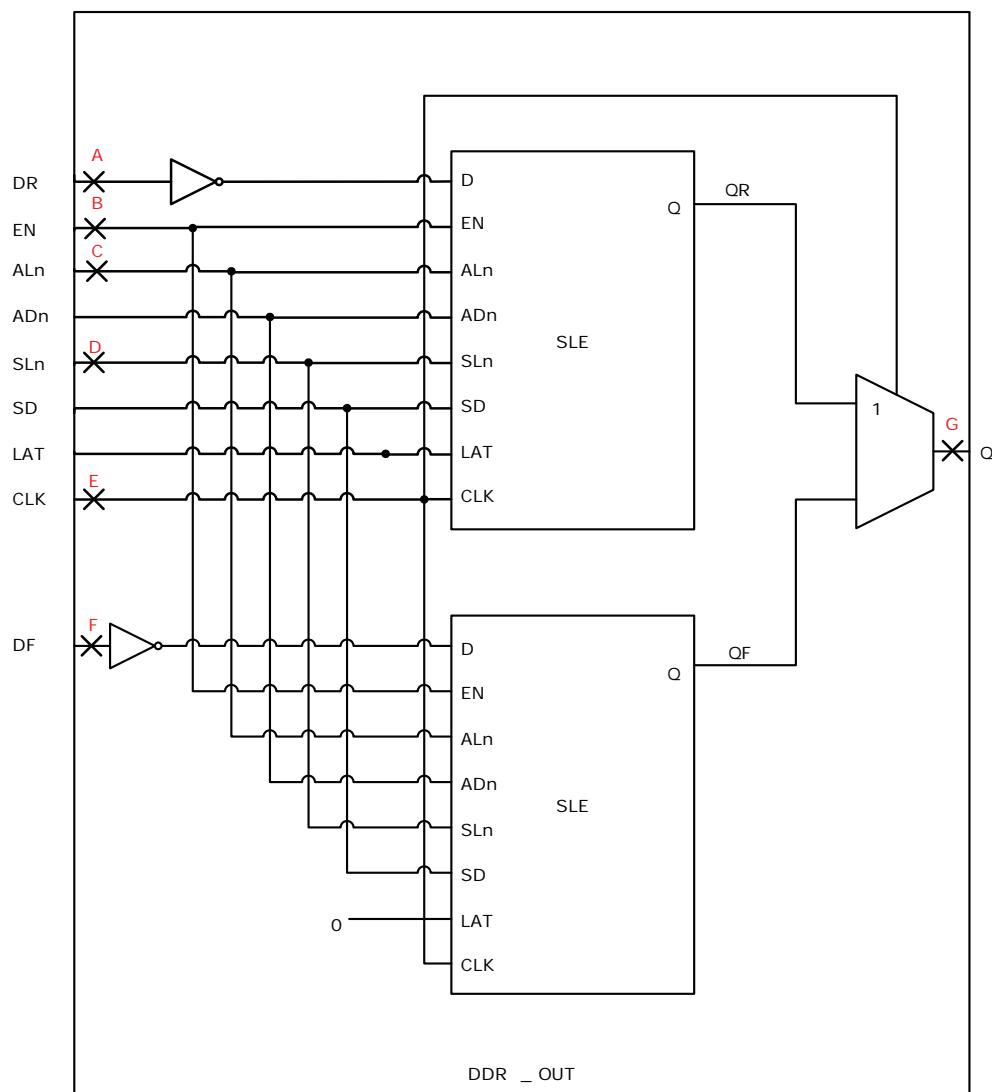
Parameter	Symbol	Min	Max	Unit
DC output logic high	V_{OH}	2.4		V
DC output logic low	V_{OL}		0.4	V

Table 33 • LVTTL/LVCMOS 3.3 V AC Maximum Switching Speed (Applicable to MSIO I/O Bank Only)

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for MSIO I/O bank)	D_{MAX}	600	Mbps	AC loading: 17 pF load, maximum drive/slew

2.3.9.4 Output DDR Module

Figure 12 • Output DDR Module



2.3.12.2 FPGA Fabric Micro SRAM (μ SRAM)

The following table lists the μ SRAM in 64×18 mode in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 237 • μ SRAM (RAM64x18) in 64×18 Mode

Parameter	Symbol	-1		-Std	
		Min	Max	Min	Max
Read clock period	T_{CY}	4	4		ns
Read clock minimum pulse width high	$T_{CLKMPWH}$	1.8	1.8		ns
Read clock minimum pulse width low	$T_{CLKMPWL}$	1.8	1.8		ns
Read pipeline clock period	T_{PLCY}	4	4		ns
Read pipeline clock minimum pulse width high	$T_{PLCLKMPWH}$	1.8	1.8		ns
Read pipeline clock minimum pulse width low	$T_{PLCLKMPWL}$	1.8	1.8		ns
Read access time with pipeline register	T_{CLK2Q}		0.266	0.313	ns
Read access time without pipeline register			1.677	1.973	ns
Read address setup time in synchronous mode	T_{ADDRSU}	0.301	0.354		ns
Read address setup time in asynchronous mode		1.856	2.184		ns
Read address hold time in synchronous mode	T_{ADDRHD}	0.091	0.107		ns
Read address hold time in asynchronous mode		-0.778	-0.915		ns
Read enable setup time	T_{RDENSU}	0.278	0.327		ns
Read enable hold time	T_{RDENHD}	0.057	0.067		ns
Read block select setup time	T_{BLKSU}	1.839	2.163		ns
Read block select hold time	T_{BLKHD}	-0.65	-0.765		ns
Read block select to out disable time (when pipelined register is disabled)	T_{BLK2Q}		2.036	2.396	ns
Read asynchronous reset removal time (pipelined clock)		-0.023	-0.027		ns
Read asynchronous reset removal time (non-pipelined clock)	T_{RSTREM}	0.046	0.054		ns
Read asynchronous reset recovery time (pipelined clock)		0.507	0.597		ns
Read asynchronous reset recovery time (non-pipelined clock)	T_{RSTREC}	0.236	0.278		ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	T_{R2Q}		0.839	0.987	ns
Read synchronous reset setup time	T_{SRSTSU}	0.271	0.319		ns
Read synchronous reset hold time	T_{SRSTHD}	0.061	0.071		ns
Write clock period	T_{CCY}	4	4		ns
Write clock minimum pulse width high	$T_{CCLKMPWH}$	1.8	1.8		ns
Write clock minimum pulse width low	$T_{CCLKMPWL}$	1.8	1.8		ns
Write block setup time	T_{BLKCSU}	0.404	0.476		ns
Write block hold time	T_{BLKCHD}	0.007	0.008		ns
Write input data setup time	T_{DINCSU}	0.115	0.135		ns
Write input data hold time	T_{DINCHD}	0.15	0.177		ns

Table 245 • JTAG Programming (eNVM Only)

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	137536	39	4	Sec
010	274816	78	9	Sec
025	274816	78	9	Sec
050	278528	84	8	Sec
060	268480	76	8	Sec
090	544496	154	15	Sec
150	544496	155	15	Sec

Table 246 • JTAG Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	439296	59	11	Sec
010	842688	107	20	Sec
025	1497408	120	35	Sec
050	2695168	162	59	Sec
060	2686464	158	70	Sec
090	4190208	266	147	Sec
150	6682768	316	231	Sec

Table 247 • 2 Step IAP Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	4	17	6	Sec
010	568784	7	23	12	Sec
025	1223504	14	33	23	Sec
050	2424832	29	52	40	Sec
060	2418896	39	61	50	Sec
090	3645968	60	84	73	Sec
150	6139184	100	132	120	Sec

The following table lists the system controller characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

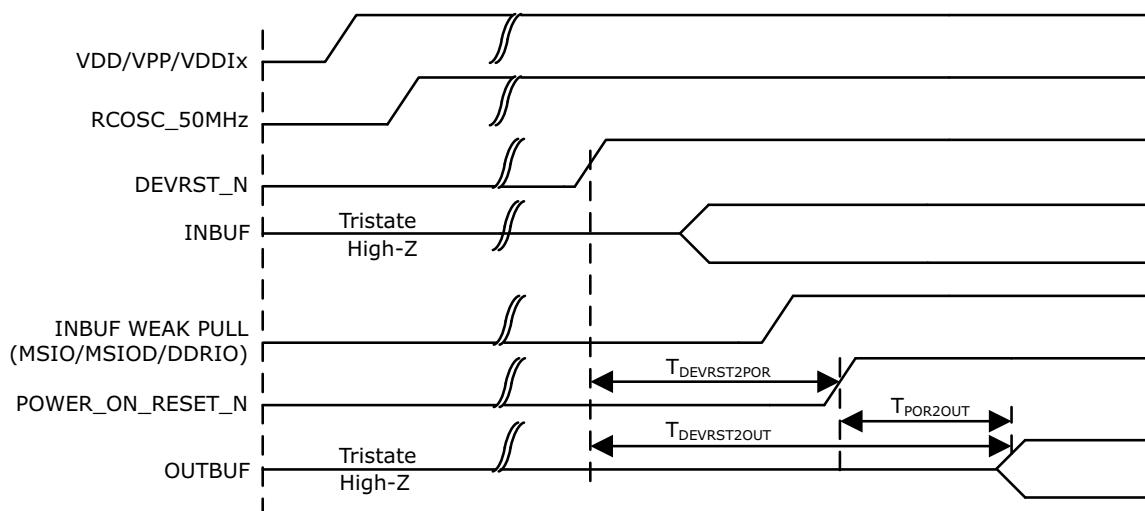
Table 286 • System Controller SPI Characteristics for All Devices

Symbol	Description	Conditions	Min	Typ	Unit
sp1	SC_SPI_SCK minimum period		20		ns
sp2	SC_SPI_SCK minimum pulse width high		10		ns
sp3	SC_SPI_SCK minimum pulse width low		10		ns
sp4 ¹	SC_SPI_SCK, SC_SPI_SDO, SC_SPI_SS rise time (10%–90%) 1	I/O configuration: LVTTL 3.3 V– 20 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C		1.239	ns
sp5 ¹	SC_SPI_SCK, SC_SPI_SDO, SC_SPI_SS fall time (10%–90%) 1	I/O configuration: LVTTL 3.3 V– 20 mA AC loading: 35 pF Test conditions: Typical voltage, 25 °C		1.245	ns
sp6	Data from master (SC_SPI_SDO) setup time		160		ns
sp7	Data from master (SC_SPI_SDO) hold time		160		ns
sp8	SC_SPI_SDI setup time		20		ns
sp9	SC_SPI_SDI hold time		20		ns

- For specific Rise/Fall Times, board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>. Use the supported I/O Configurations for the System Controller SPI in the following table.

Table 287 • Supported I/O Configurations for System Controller SPI (for MSIO Bank Only)

Voltage Supply	I/O Drive Configuration	Unit
3.3 V	20	mA
2.5 V	16	mA
1.8 V	12	mA
1.5 V	8	mA
1.2 V	4	mA

Figure 20 • DEVRST_N to Functional Timing Diagram for IGLOO2

2.3.27 Flash*Freeze Timing Characteristics

The following table lists the Flash*Freeze entry and exit times in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 293 • Flash*Freeze Entry and Exit Times

Parameter	Symbol	Entry/Exit Timing FCLK = 100MHz		Entry/Exit Timing FCLK = 3 MHz		
		150	050	All Devices	Unit	Conditions
Entry time	TFF_ENTRY	160	150	320	μs	eNVM and MSS/HPMS PLL = ON
		215	200	430	μs	eNVM and MSS/HPMS PLL = OFF
Exit time with respect to the MSS PLL Lock	TFF_EXIT	100	100	140	μs	eNVM and MSS/HPMS PLL = ON during F*F
		136	120	190	μs	eNVM = ON and MSS/HPMS PLL = OFF during F*F and MSS/HPMS PLL turned back on at exit
	TFF_EXIT	200	200	285	μs	eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit
		200	200	285	μs	eNVM = OFF and MSS/HPMS PLL = ON during F*F and eNVM turned back on at exit

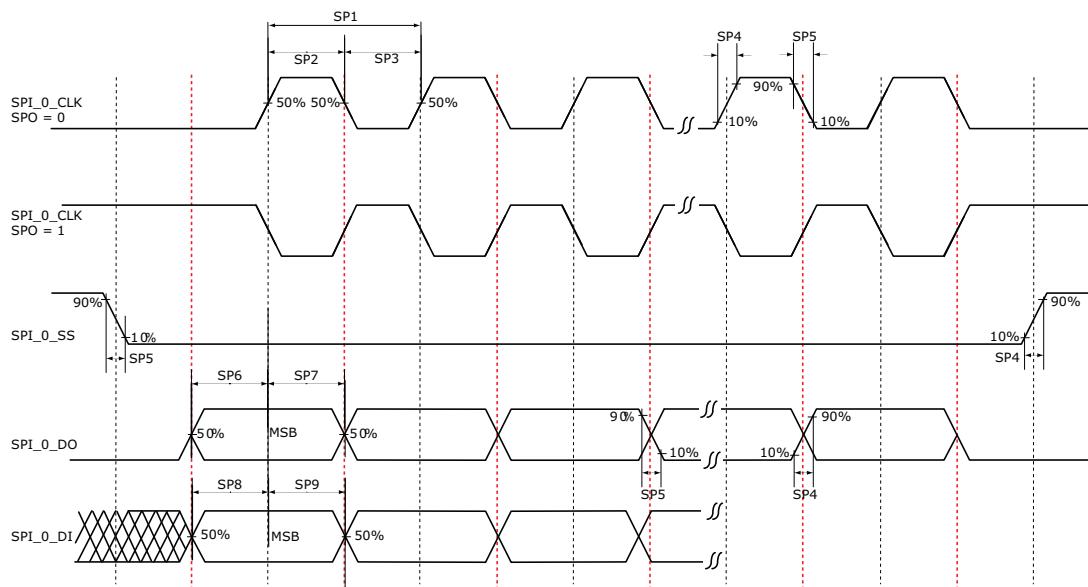
2.3.30 SerDes Electrical and Timing AC and DC Characteristics

PCIe is a high-speed, packet-based, point-to-point, low-pin-count, serial interconnect bus. The IGLOO2 and SmartFusion2 SoC FPGAs has up to four hard high-speed serial interface blocks. Each SerDes block contains a PCIe system block. The PCIe system is connected to the SerDes block.

The following table lists the transmitter parameters in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 296 • Transmitter Parameters

Symbol	Description	Min	Max	Unit
VTX-DIFF-PP	Differential swing (2.5 Gbps, 5.0 Gbps)	0.8	1.2	V
VTX-CM-AC-P	Output common mode voltage (2.5 Gbps)	20		mV
VTX-CM-AC-PP	Output common mode voltage (5.0 Gbps)	100		mV
VTX-RISE-FALL	Rise and fall time (20% to 80%, 2.5 Gbps)	0.125		UI
	Rise and fall time (20% to 80%, 5.0 Gbps)	0.15		UI
ZTX-DIFF-DC	Output impedance–differential	80	120	Ω
LTX-SKEW	Lane-to-lane TX skew within a SerDes block (2.5 Gbps)	500 ps + 2 UI		ps
	Lane-to-lane TX skew within a SerDes block (5.0 Gbps)	500 ps + 4 UI		ps
RLTX-DIFF	Return loss differential mode (2.5 Gbps)	-10		dB
	Return loss differential mode (5.0 Gbps)	-10		dB
	0.05 GHz to 1.25 GHz	-10		dB
	1.25 GHz to 2.5 GHz	-8		dB
RLTX-CM	Return loss common mode (2.5 Gbps, 5.0 Gbps)	-6		dB
TX-LOCK-RST	Transmit PLL lock time from reset	10		μs
VTX-AMP	100 mV setting	90	150	mV
	400 mV setting	320	480	mV
	800 mV setting	660	940	mV
	1200 mV setting	950	1400	mV

Figure 22 • SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1)

2.3.32 CAN Controller Characteristics

The following table lists the CAN controller characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 306 • CAN Controller Characteristics

Parameter	Description	-1	-Std	Unit
FCANREFCLK ¹	Internally sourced CAN reference clock frequency	160	136	MHz
BAUDCANMAX	Maximum CAN performance baud rate	1	1	Mbps
BAUDCANMIN	Minimum CAN performance baud rate	0.05	0.05	Mbps

1. PCLK to CAN controller must be a multiple of 8 MHz.

2.3.33 USB Characteristics

The following table lists the USB characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 307 • USB Characteristics

Parameter	Description	-1	-Std	Unit
FUSBREFCLK	Internally sourced USB reference clock frequency	166	142	MHz
TUSBCLK	USB clock period	16.66	16.66	ns
TUSBPD	Clock to USB data propagation delay	9.0	9.0	ns
TUSBSU	Setup time for USB data	6.0	6.0	ns
TUSBHD	Hold time for USB data	0	0	ns

Table 310 • SPI Characteristics for All Devices (continued)

Symbol	Description	Min	Typ	Max	Unit	Conditions
sp2	SPI_[0 1]_CLK minimum pulse width high					
	SPI_[0 1]_CLK = PCLK/2	6			ns	
	SPI_[0 1]_CLK = PCLK/4	12.05			ns	
	SPI_[0 1]_CLK = PCLK/8	24.1			ns	
	SPI_[0 1]_CLK = PCLK/16	0.05			μs	
	SPI_[0 1]_CLK = PCLK/32	0.095			μs	
	SPI_[0 1]_CLK = PCLK/64	0.195			μs	
	SPI_[0 1]_CLK = PCLK/128	0.385			μs	
sp3	SPI_[0 1]_CLK minimum pulse width low					
	SPI_[0 1]_CLK = PCLK/2	6			ns	
	SPI_[0 1]_CLK = PCLK/4	12.05			ns	
	SPI_[0 1]_CLK = PCLK/8	24.1			ns	
	SPI_[0 1]_CLK = PCLK/16	0.05			μs	
	SPI_[0 1]_CLK = PCLK/32	0.095			μs	
	SPI_[0 1]_CLK = PCLK/64	0.195			μs	
	SPI_[0 1]_CLK = PCLK/128	0.385			μs	
sp4	SPI_[0 1]_CLK, SPI_[0 1]_DO, SPI_[0 1]_SS rise time (10%–90%) ¹		2.77		ns	I/O Configuration: LVCMOS 2.5 V - 8 mA AC loading: 35 pF test conditions: Typical voltage, 25 °C
sp5	SPI_[0 1]_CLK, SPI_[0 1]_DO, SPI_[0 1]_SS fall time (10%–90%) ¹		2.906		ns	I/O Configuration: LVCMOS 2.5 V - 8 mA AC loading: 35 pF test conditions: Typical voltage, 25 °C
SPI master configuration (applicable for 005, 010, 025, and 050 devices)						
sp6m	SPI_[0 1]_DO setup time ²	(SPI_x_CLK_period/2) – 8.0			ns	
sp7m	SPI_[0 1]_DO hold time ²	(SPI_x_CLK_period/2) – 2.5			ns	
sp8m	SPI_[0 1]_DI setup time ²	12			ns	
sp9m	SPI_[0 1]_DI hold time ²	2.5			ns	
SPI slave configuration (applicable for 005, 010, 025, and 050 devices)						
sp6s	SPI_[0 1]_DO setup time ²	(SPI_x_CLK_period/2) – 17.0			ns	
sp7s	SPI_[0 1]_DO hold time ²	(SPI_x_CLK_period/2) + 3.0			ns	
sp8s	SPI_[0 1]_DI setup time ²	2			ns	
sp9s	SPI_[0 1]_DI hold time ²	7			ns	